

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Michael Geva, et al.

Serial No.:

09/757,099

Filed:

For:

LECTRONIC DEVICE HAVING A BARRIER REGION INCLUDING ALUMINUM AND A METHOD OF MANUFACTURE 7/27/0 / THEREFOR

Group No.:

Commissioner for Patents Washington, D. C. 20231

I hereby certify that this correspondence is being deposited with the United States Postal Service

Sir:

**INFORMATION DISCLOSURE STATEMENT** 

In accordance with 37 C.F.R. §1.56 and the provisions of 37 C.F.R. §§1.97 and 1.98 and §609 of the Manual of Patent Examining Procedure, Applicant hereby makes a disclosure of the patents, publications and other information listed below and on the accompanying form PTO-1449, which may be potentially material to the patentability of the invention disclosed in the abovereferenced application. Pursuant to § 1.97(e) the Applicant hereby states that each item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the information disclosure statement.

U.S. Patent No.	<u>Inventor</u>	<u>Date</u>
5,882,951	Bhat	March 16, 1999
5,559,910	Taga et al.	September 24, 1996
4,438,446	Tsang	March 20, 1984
Foreign Patent No.	Country	<u>Date</u>
97/50133	WO	31 December 1997
97/40560	WO	30 October 1997
0 715 380 A1	EP	5 June 1996
0 557 638 A2	EP	1 September 1993
0 518 320 A2	EP	16 December 1992

## Ref:

K. Schimpf, J. Hollfelder, M. Horstmann, M. Marso, H. Hardtdegen and P. Kordos; "0.2um T-gate InP/InGaAs/InP pHEMT with InGaP diffusion barrier layer grown by LP-MOCVD using and N<sub>2</sub>-carrier"; IPRM, SCHWABISCH-GMUND, 1996, pgs. 666-669 XP-002169035.

Applicant hereby certifies that each item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the statement.

As attorney for the Applicant, I am signing below on the basis of the information supplied by an individual designated in § 1.56(c).

Respectfully submitted,

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